



DMN6075SQ

60V N-CHANNEL ENHANCEMENT MODE MOSFET

Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
60V	$85m\Omega @ V_{GS} = 10V$	2.5A
607	120mΩ @ $V_{GS} = 4.5V$	2.0A

Description and Applications

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- DC-DC Converters
- Power Management Functions
- Backlighting

Features and Benefits

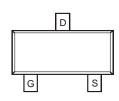
- N MOSFET
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN6075SQ is suitable for automotive applications requiring specific change control and is AEC-Q101 qualified, is PPAP capable, and is manufactured in IATF16949:2016 certified facilities.

Mechanical Data

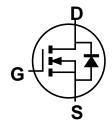
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (Approximate)







Top View



Equivalent Circuit

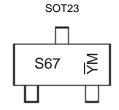
Ordering Information (Note 4)

Part Number	Case	Packaging
DMN6075SQ-7	SOT23	3000/Tape & Reel
DMN6075SQ-13	SOT23	10000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



 $\underline{S}67$ = Product Type Marking Code $\overline{Y}M$ = Date Code Marking \overline{Y} = Year (ex: G = 2019) M = Month (ex: 9 = September)

Date Code Key

Year	2019	2020	20	021	2022	2023	3	2024	2025	202	26	2027
Code	G	Н		1	J	K		Г	M	N	ı	0
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	l Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Characteristic		Symbol	Value	Unit		
Drain-Source Voltage		V _{DSS}	60	V		
Gate-Source Voltage	V _{GSS}	±20	V			
Continuous Proin Correct (Note 5) / 40)/	Steady	T _A = +25°C	ı	2.0	۸	
Continuous Drain Current (Note 5) V _{GS} = 10V	State	T _A = +70°C	ID	1.5	Α	
	Steady	T _A = +25°C	I _D	2.5	^	
Continuous Drain Current (Note 6) V _{GS} = 10V	State	T _A = +70°C		2.0	А	
Maximum Body Diode Forward Current (Note 5)		Is	2.0	Α		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	I _{DM}	12	Α			
Pulsed Source Current (10µs Pulse, Duty Cycle = 1	I _{SM}	12	А			

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Total Power Dissipation (Note 5)	T _A = +25°C	D	0.8	W	
Total Fower Dissipation (Note 5)	T _A = +70°C	P_D	0.5		
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	157	°C/W	
Total Davier Discipation (Nata C)	T _A = +25°C	-	1.15	W	
Total Power Dissipation (Note 6)	T _A = +70°C	P_D	0.7	VV	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	110	°C/W	
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	1	1	1.0	μA	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	1	1	±100	nA	$V_{GS} = \pm 16V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)	_						
Gate Threshold Voltage	$V_{GS(TH)}$	1	_	3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	D	1	69	85	mΩ	$V_{GS} = 10V, I_D = 3.2A$	
Static Dialif-Source Off-Resistance	R _{DS(ON)}	_	75	120	mt7	$V_{GS} = 4.5V, I_D = 2.8A$	
Diode Forward Voltage	V_{SD}	_	0.8	1.2	V	$V_{GS} = 0V, I_{S} = 2.5A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	_	606	_	pF		
Output Capacitance	Coss	_	32.6	_	pF	$V_{DS} = 20V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	24.6	_	pF	1 = 1.01/11/12	
Gate Resistance	Rg	_	1.5	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 10V)	Qg	_	12.3	_	nC		
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	5.6	_	nC	V	
Gate-Source Charge	Q_{gs}	_	1.7	_	nC	$V_{DS} = 30V, I_{D} = 3A$	
Gate-Drain Charge	Q _{gd}	_	1.9	_	nC		
Turn-On Delay Time	t _{D(ON)}	-	3.5	_	ns		
Turn-On Rise Time	t _R	-	4.1	_	ns	$V_{GS} = 10V, V_{DS} = 30V,$	
Turn-Off Delay Time	t _{D(OFF)}	-	35	_	ns	$R_g = 20\Omega$, $R_L = 50\Omega$	
Turn-Off Fall Time	t _F	_	11	_	ns]	

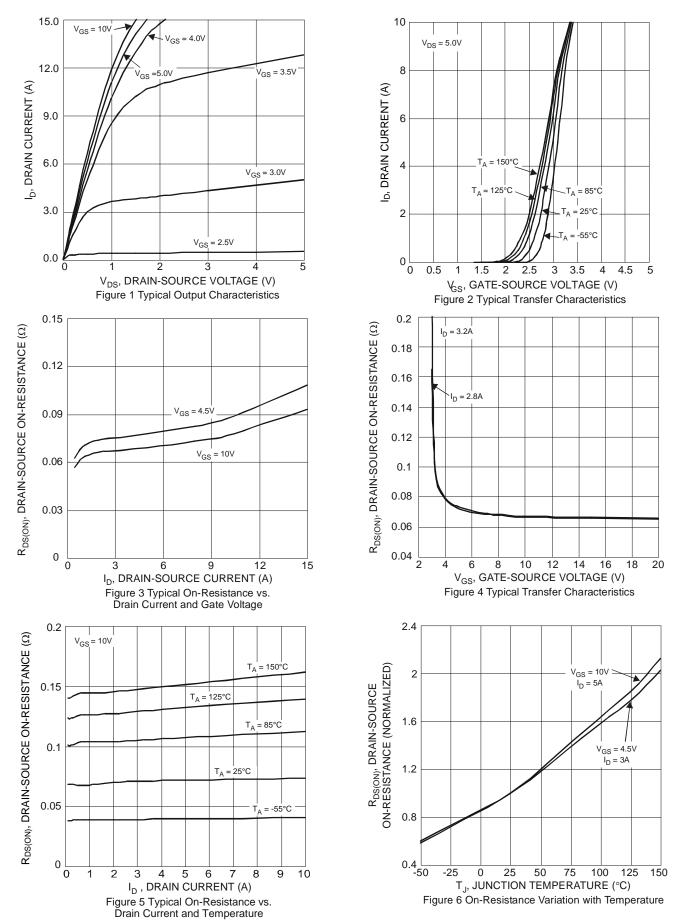
Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

^{6.} Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1-inch square copper plate.

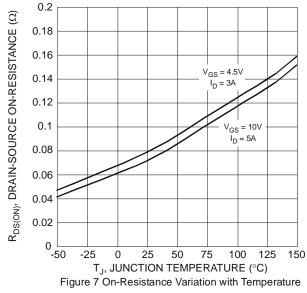
^{7.} Short duration pulse test used to minimize self-heating effect.

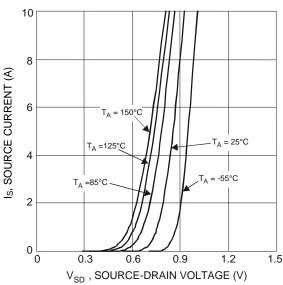
^{8.} Guaranteed by design. Not subject to product testing.

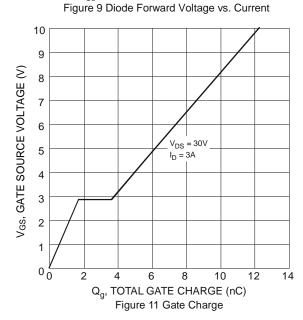












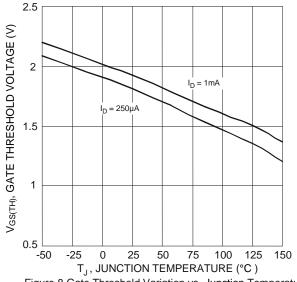


Figure 8 Gate Threshold Variation vs. Junction Temperature

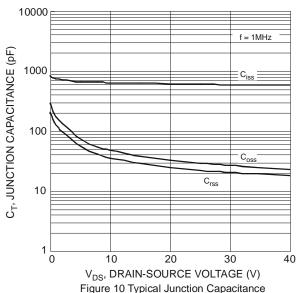
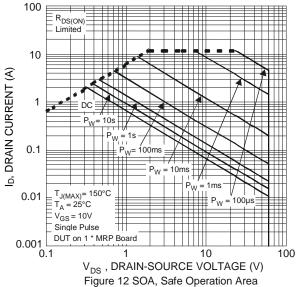


Figure 10 Typical Junction Capacitance





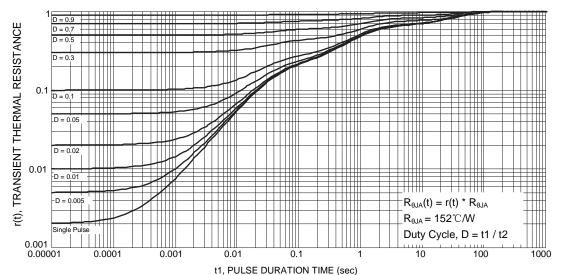
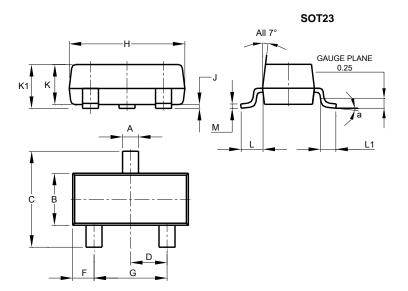


Figure 13 Transient Thermal Resistance



Package Outline Dimensions

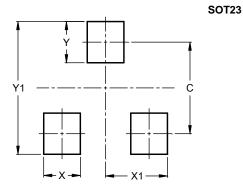
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
V1	2.0



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